

Photo DMOS-FET Relay

Description

The **LT618** is a miniature 1-Form A solid state relay in an 4 pin SMD package that employs optically coupled MOSFET technology to provide 3750V of input to output isolation. The optically coupled input is controlled by a highly efficient GaAlAs infrared LED and MOS FETs on the output side.

Features

- Low driver power requirements (TTL/CMOS Compatible)
- No moving parts
- High reliability
- Arc-Free with no snubbing circuits
- 3750Vrms Input/Output isolation

Applications

- Telecommunications (PC, Electronic notepad)
- Measuring and Testing equipment
- Industrial control
- Security equipments
- High speed inspection machine

Outline Dimensions

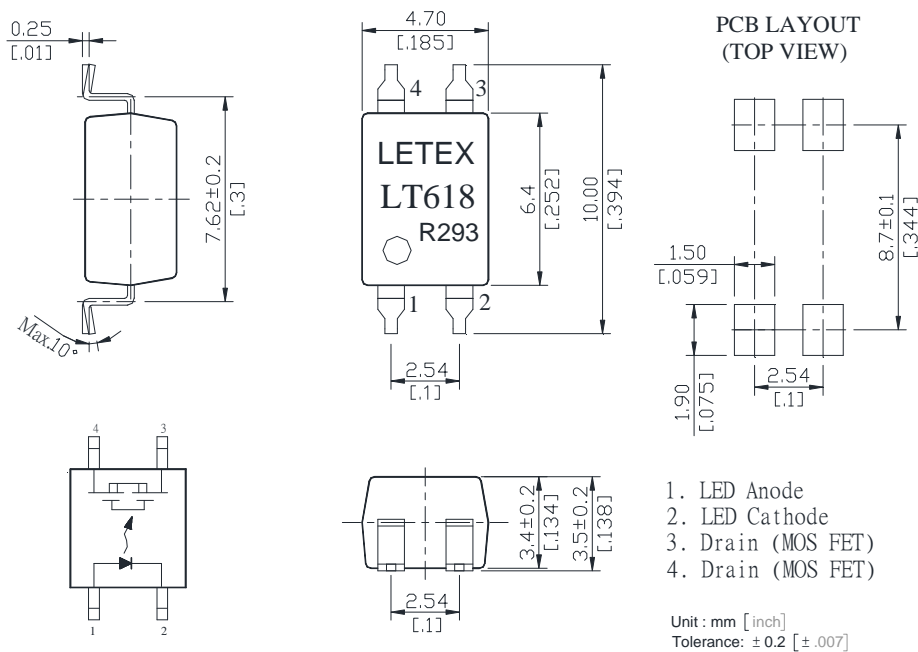


Photo DMOS-FET Relay Specifications

Part Name: LT618

(Load voltage: 40V / Load current: 2.0A)

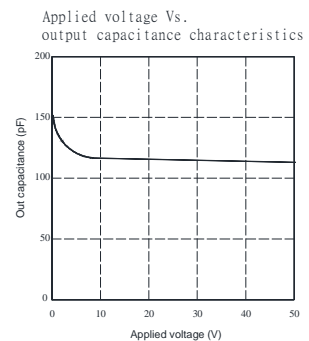
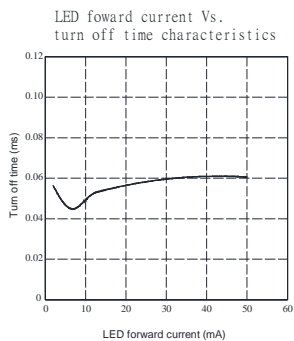
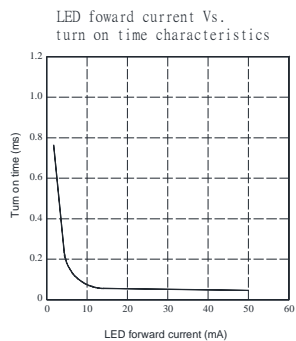
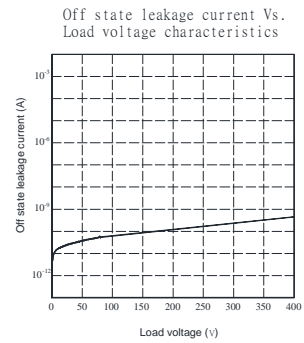
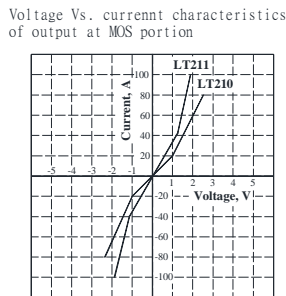
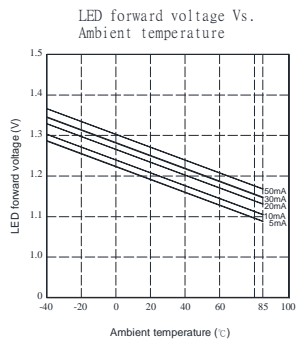
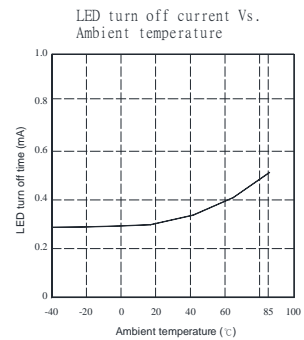
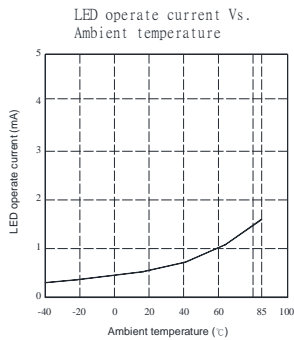
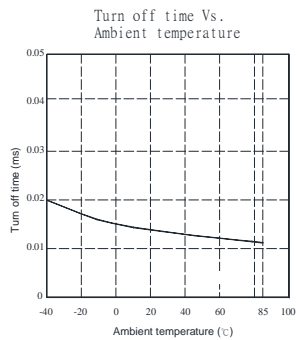
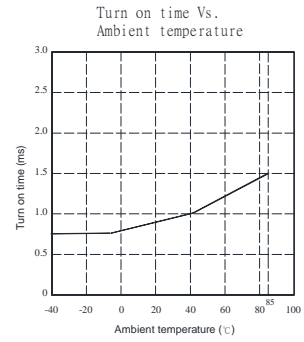
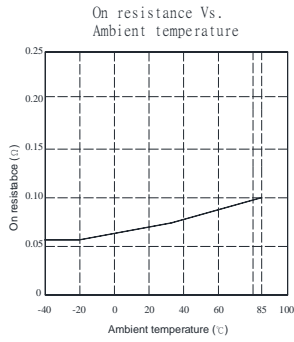
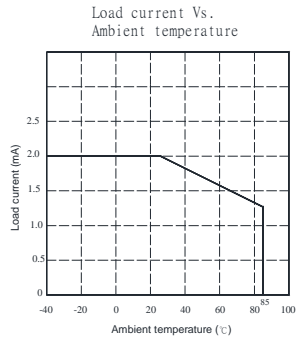
Absolute Maximum Ratings (Ambient Temperature: 25°C)

Item		Symbol	Value	Units	Note
Input	Continuous LED Current	I _F	50	mA	
	Peak LED Current	I _{FP}	1000	mA	f=100Hz, duty=1%
	LED Reverse Voltage	V _R	5	V	
	Input Power Dissipation	P _{In}	75	mW	
Output	Load Voltage	V _L	40	V(AC peak or DC)	
	Load Current	I _L	2.0	A	
	Peak Load Current	I _{Peak}	2.5	A	100ms(1 pulse)
	Output Power Dissipation	P _{out}	1.8	W	
Total Power Dissipation		P _T	2	W	
I/O Breakdown Voltage		V _{I/O}	3750	V _{rms}	RH=60%, 1min
Operating Temperature		T _{Opr}	-40 to +85	°C	
Storage Temperature		T _{Stg}	-40 to +100	°C	
Pin Soldering Temperature		T _{Sol}	260	°C	10 sec max.

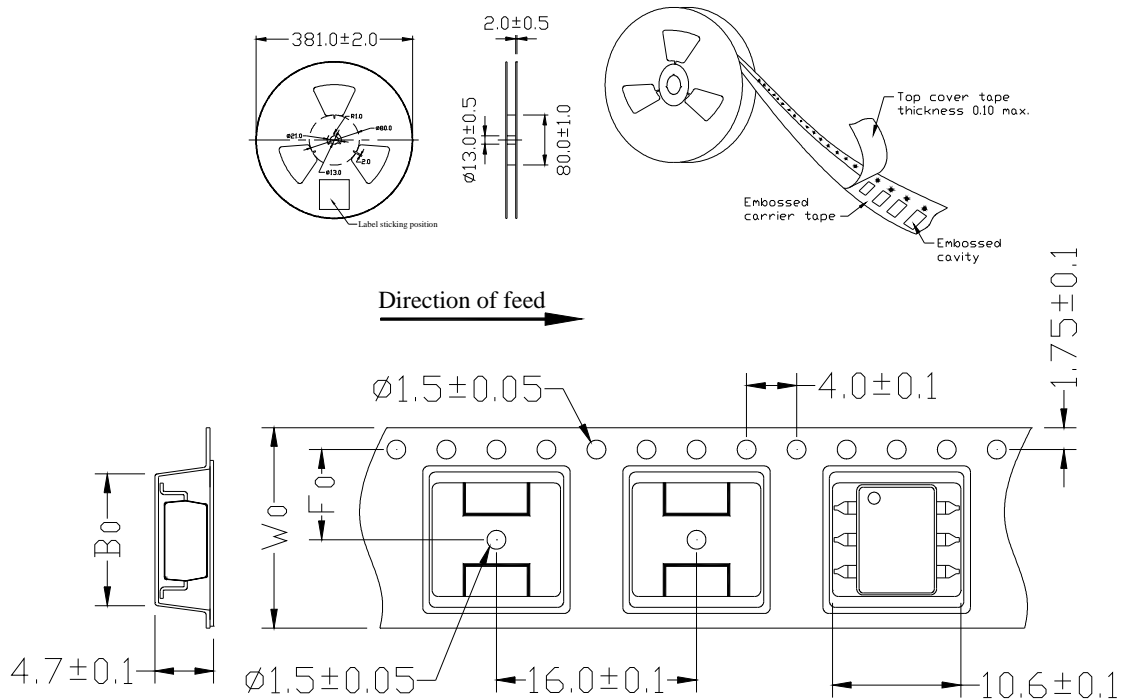
Electrical Specifications (Ambient Temperature: 25°C)

Item		Symbol	MIN.	TYP.	MAX.	Units	Conditions
Input	LED Forward Voltage	V _F		1.2	1.4	V	I _F =10mA
	Operation LED Current	I _{F On}		0.5	3.0	mA	
	Recovery LED Current	I _{F Off}		0.35	0.5	mA	
	Recovery LED Voltage	V _{F Off}	0.5			V	
Output	On-Resistance	R _{On}		0.06	0.1	Ω	I _F =5mA, I _L =100mA, Time to flow is within 1 sec.
	Off-State Leakage Current	I _{Leak}			1	uA	V _L =Rating
	Output Capacitance	C _{Out}		150		pF	V _L =0, f=1MHz
Transmission	Turn-On Time	T _{On}		0.8	1.5	ms	I _F =5mA, I _L =100mA,
	Turn-Off Time	T _{Off}		0.02	0.5	ms	
Coupled	I/O Isolation Resistance	R _{I/O}	10 ¹⁰			Ω	DC500V
	I/O Capacitance	C _{I/O}		0.8	1.5	pF	f=1MHz

Reference Data



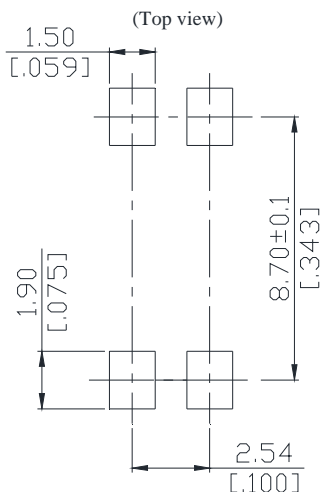
Taping Specifications for Surface Mount Devices



Unit: mm

TYPE	B0±0.1	F0±0.1	W0±0.1	13" REEL/PCS
4P	5.3	7.5	16	1000
6P	9.4	7.5	16	1000
8P	10.3	11.5	24	1000

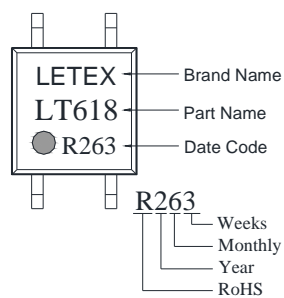
Recommended Mounting Pad



Unit : mm [inch]
Tolerance : ±0.1

Marking

(Each photo MOS Relay shall be marked with the following information)



- Note:
1. There shall be leader of 230 mm minimum which may consist of carrier and or cover tape follower by a minimum of 160 mm of carrier tape sealed with cover tape.
 2. There shall be a minimum of 160 mm of empty component pockets sealed with cover tape.
 3. Devices are pockets in accordance with EIA standard EIA-481-A and specifications given above.